Scopus

文献数

Ochoa-Martínez, E., Barrutia, L., Ochoa, M., Barrigón, E., García, I., Rey-Stolle, I., Algora, C., Basa, P., Kronome, G., Gabás, M. Refractive indexes and extinction coefficients of n- and p-type doped GalnP, AllnP and AlGalnP for multijunction solar cells (2018) Solar Energy Materials and Solar Cells, 174, pp. 388-396.

DOI: 10.1016/j.solmat.2017.09.028

- ^a The Nanotech Unit, Depto. Física Aplicada I, Lab. de Materiales & Superficies, Universidad de Málaga, Málaga, Spain
- ^b Instituto de Energía Solar, Universidad Politécnica de Madrid, Madrid, Spain
- ^c Semilab Semiconductor Physics Laboratory Co. Ltd., Prielle K. u. 2, Budapest, Hungary

抄録 (Abstract)

The optical properties of p-type, n-type and nominally undoped (AlxGa1-x)yIn1-yP layers have been determined in a wide spectral range. The layers under study have been chosen with compositions and dopant concentrations which make them interesting for their use in III-V multijunction solar cells. The layers have been measured by variable angle spectroscopic ellipsometry and, irrespective of composition and doping, their optical response has been modelled using the same model dielectric function consisting of two asymmetric Tauc-Lorentz oscillators and a 3D-M0 Adachi term. The results show that transition energy values change with layer composition, whilst for layers of the same material (i.e. GalnP or AllnP), the band-gap transition energy E0 shows a strong dependence on the order parameter. The refractive indexes and extinction coefficients deduced from the ellipsometric data have been used to fit reflectance measurements for the same layers and an excellent agreement has been achieved, thus validating the model dielectric function proposed for this kind of materials. © 2017 Elsevier B.V.

著者キーワード

Doped-GalnP (-AllnP, -AlGalnP); III-V semiconductor layers; Multijunction solar cells; Order parameter; Spectroscopic ellipsometry

文献タイプ: Article 情報源: Scopus



Copyright © 2017 Elsevier B.V. All rights reserved. Scopus® is a registered trademark of Elsevier B.V.

